

Vishay General Semiconductor

### **High Current Density Surface Mount Glass-Passivated Rectifiers**

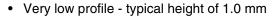




DO-220AA (SMP)

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	1 A					
$V_{RRM}$	100 V to 1000 V					
I <sub>R</sub>	1 μΑ					
V <sub>F</sub>	0.95 V					
T <sub>J</sub> max.	150 °C					

#### **FEATURES**





· Ideal for automated placement



· Glass passivated chip junction

· Low forward voltage drop

· Low thermal resistance

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

General purpose, polarity protection, and rail-to-rail protection in both consumer and automotive applications.

#### **MECHANICAL DATA**

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2

whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	S1PB	S1PD	S1PG	S1PJ	S1PK	S1PM	UNIT
Device marking code		SB	SD	SG	SJ	SK	SM	
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	100	200	400	600	800	1000	V
Average forward current	I <sub>F(AV)</sub>	1.0						Α
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30					Α	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150					°C	

### Vishay General Semiconductor



<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)										
PARAMETER	TEST CO	ONDITIONS	SYMBOL	S1PB	S1PD	S1PG	S1PJ	S1PK	S1PM	UNIT
Maximum instantaneous forward voltage (1)	$I_F = 1.0 A$ $I_F = 1.0 A$	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	V <sub>F</sub>	1.1 0.95						V
Maximum reverse current (1)	rated V <sub>R</sub>	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	1.0 1.0 50 100					μΑ	
Typical reverse recovery time	I <sub>F</sub> = 0.5 A, I <sub>rr</sub> = 0.25 A	I <sub>R</sub> = 1.0 A,	t <sub>rr</sub>	1.8						μs
Typical junction capacitance time	4.0 V, 1 MF	łz	CJ	6.0					pF	

#### Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	BOL S1PB S1PD S1PG S1PJ S1PK S1PM					S1PM	UNIT
Typical thermal resistance <sup>(1)</sup>	$egin{array}{l} R_{ hetaJA} \ R_{ hetaJL} \ R_{ hetaJC} \end{array}$	105 15 20					°C/W	

#### Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas.  $R_{\theta JC}$  is measured at the terminal of cathode band.  $R_{\theta JC}$  is measured at the top centre of the body

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
S1PJ-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel			
S1PJ-E3/85A	0.024	85A	10000	13" diameter plastic tape and reel			
S1PJHE3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel			
S1PJHE3/85A (1)	0.024	85A	10000	13" diameter plastic tape and reel			

#### Note:

(1) Automotive grade AEC Q101 qualified

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

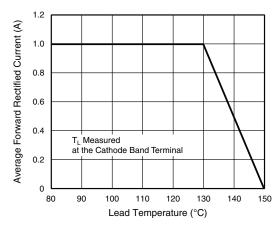


Figure 1. Maximum Forward Current Derating Curve

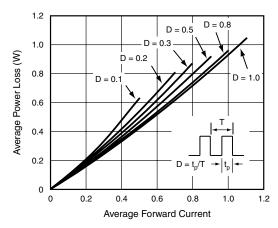


Figure 2. Forward Power Loss Characteristics



# Vishay General Semiconductor

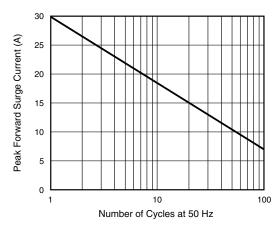


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

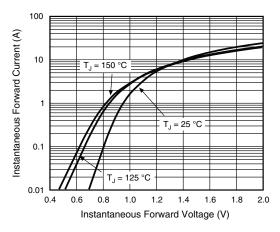


Figure 4. Typical Instantaneous Forward Characteristics

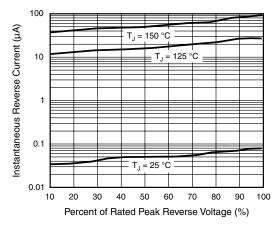


Figure 5. Typical Reverse Leakage Characteristics

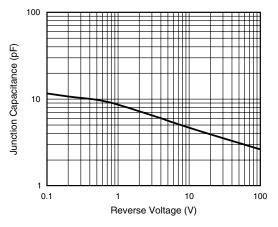


Figure 6. Typical Junction Capacitance

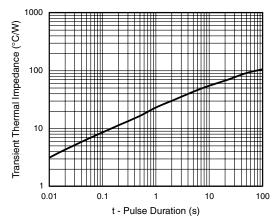


Figure 7. Typical Transient Thermal Impedance

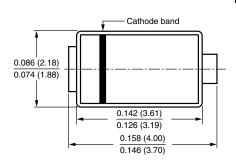
### S1PB thru S1PM

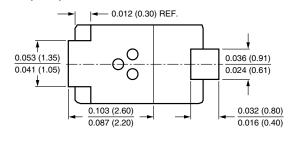
## Vishay General Semiconductor

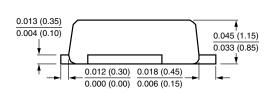


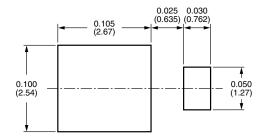
### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### DO-220AA (SMP)









### **Legal Disclaimer Notice**



Vishay

### **Notice**

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.

Document Number: 91000 www.vishay.com Revision: 08-Apr-05